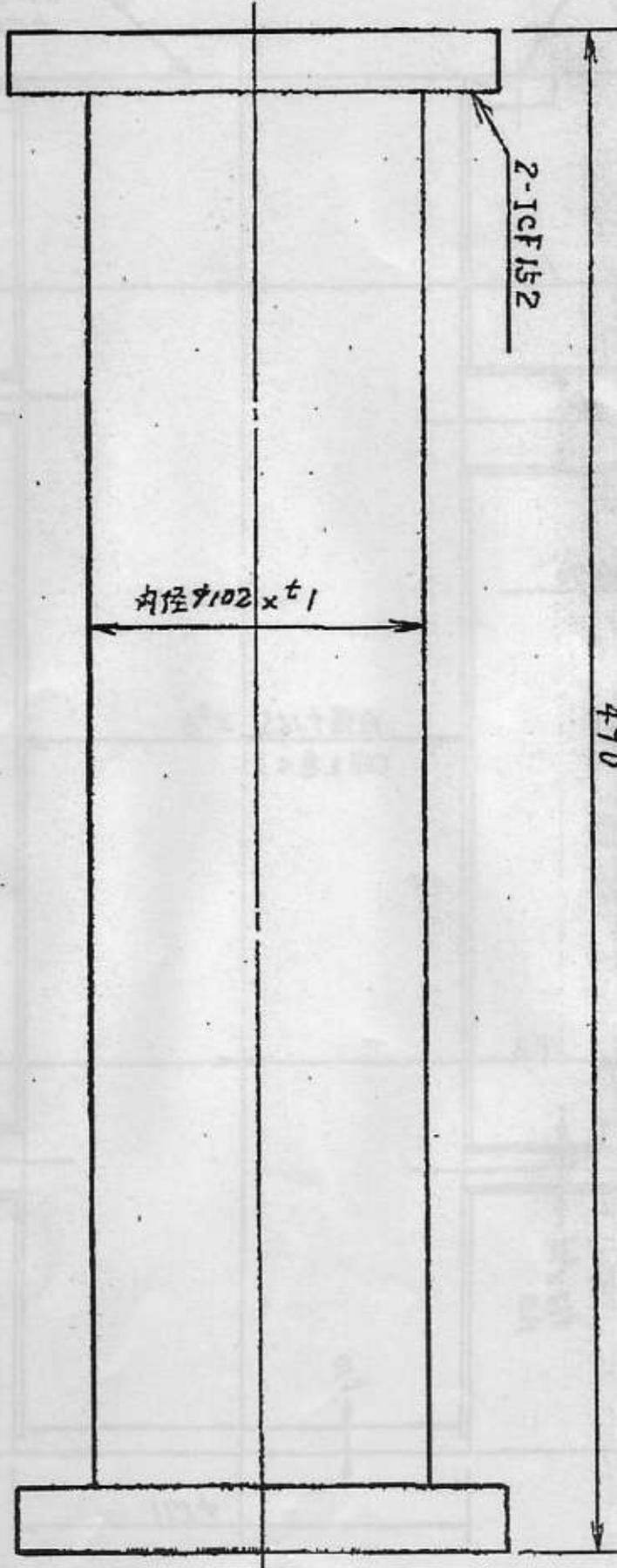


Handwritten notes and sketches in the right margin:

- A small sketch of a component at the top right.
- A larger, more complex sketch in the middle right, possibly showing a cross-section or a different view of the assembly.
- Handwritten text in Japanese, including "図" (drawing) and "図" (drawing).

6/10

④



2-1CF152

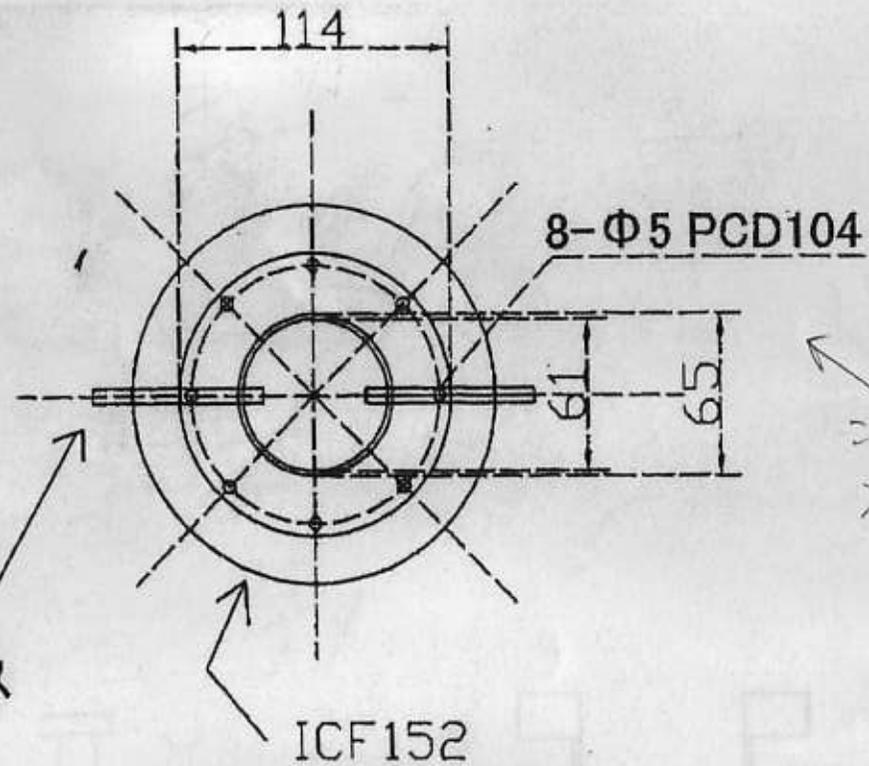
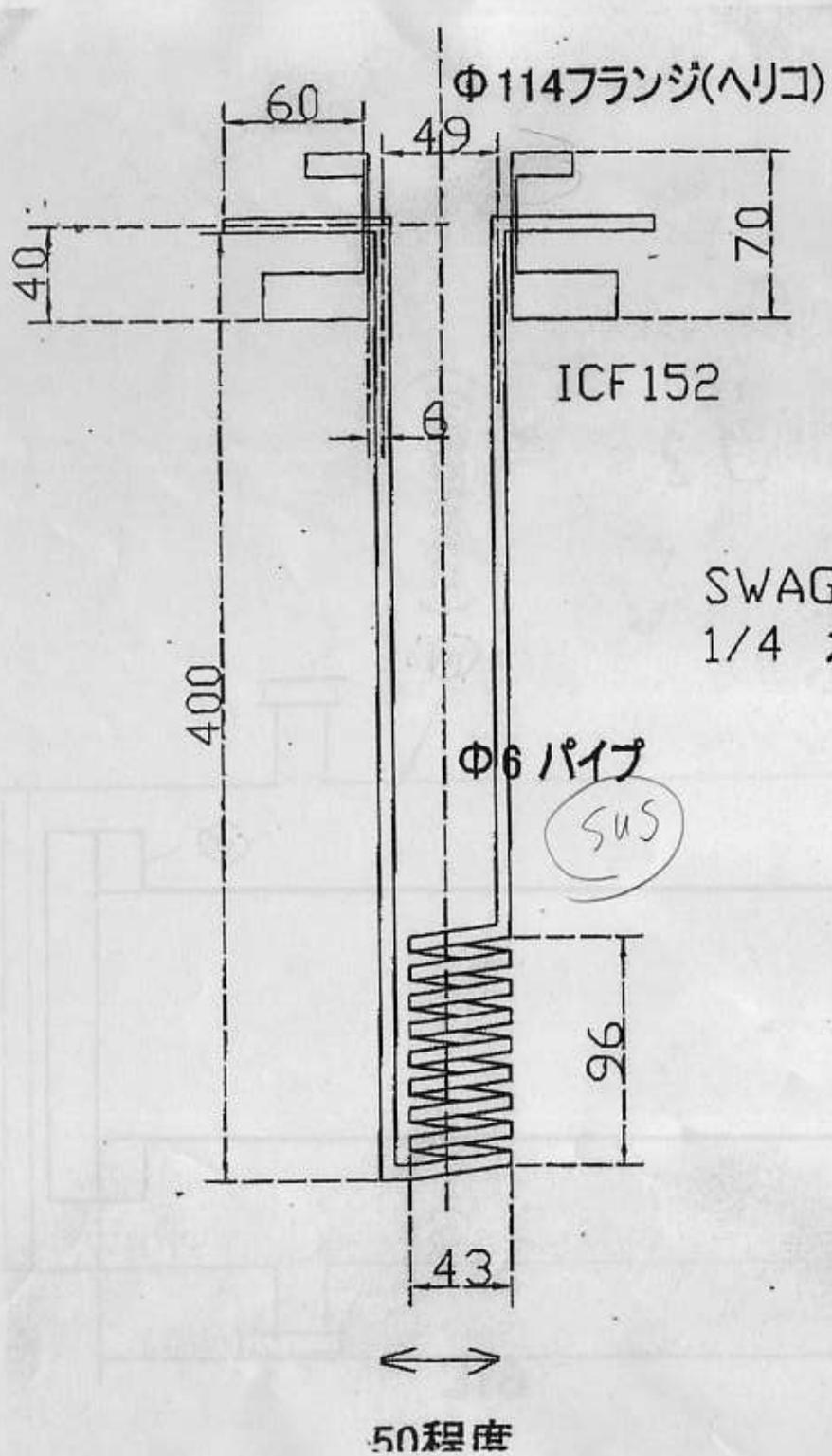
内径 $\phi 102 \times t_1$

490

SUS 304

1/2

15



SWAGE
1/4 ヌス

これは大3号サイズの
冷凍機用ニツプル。

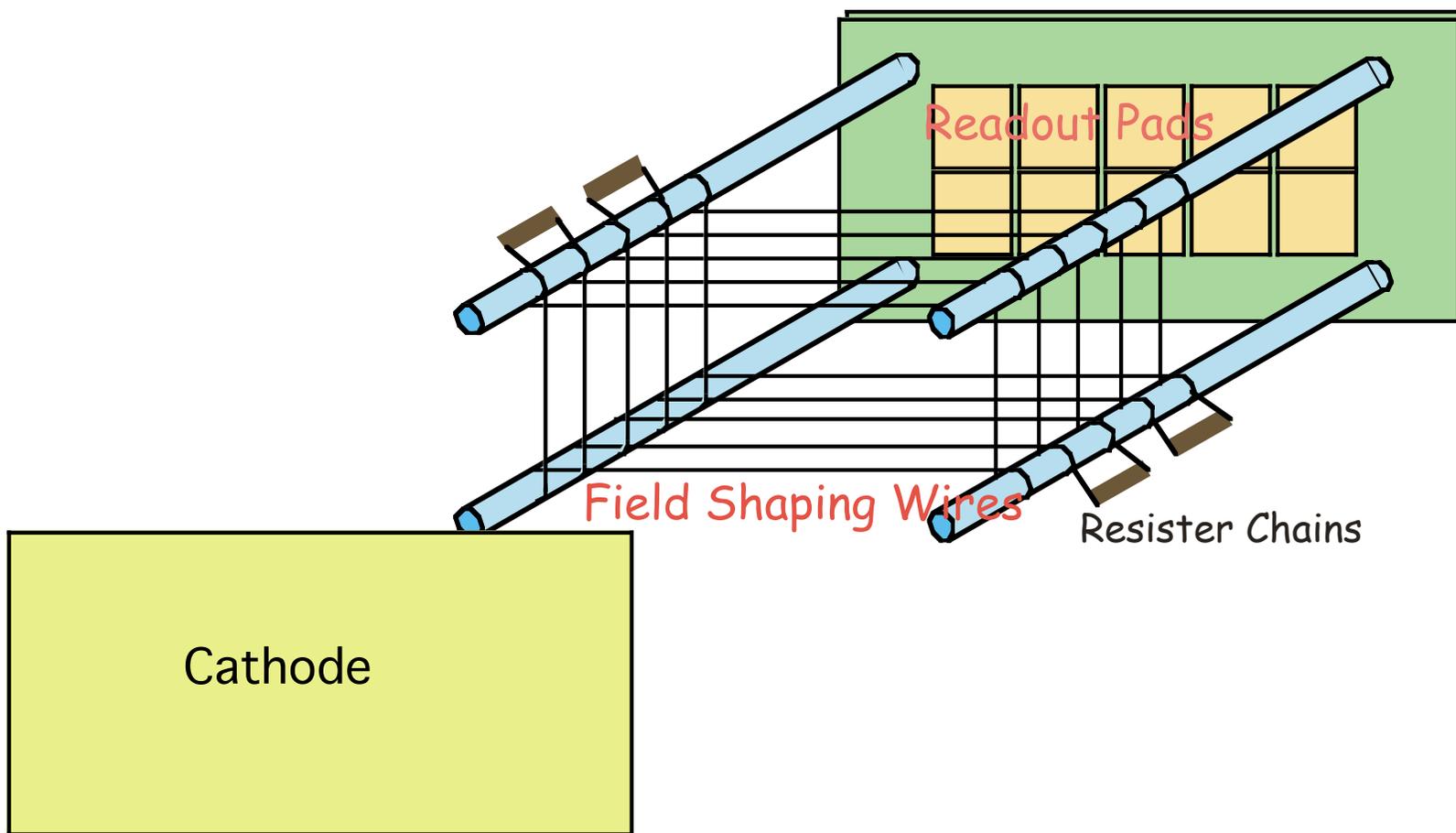
⑦

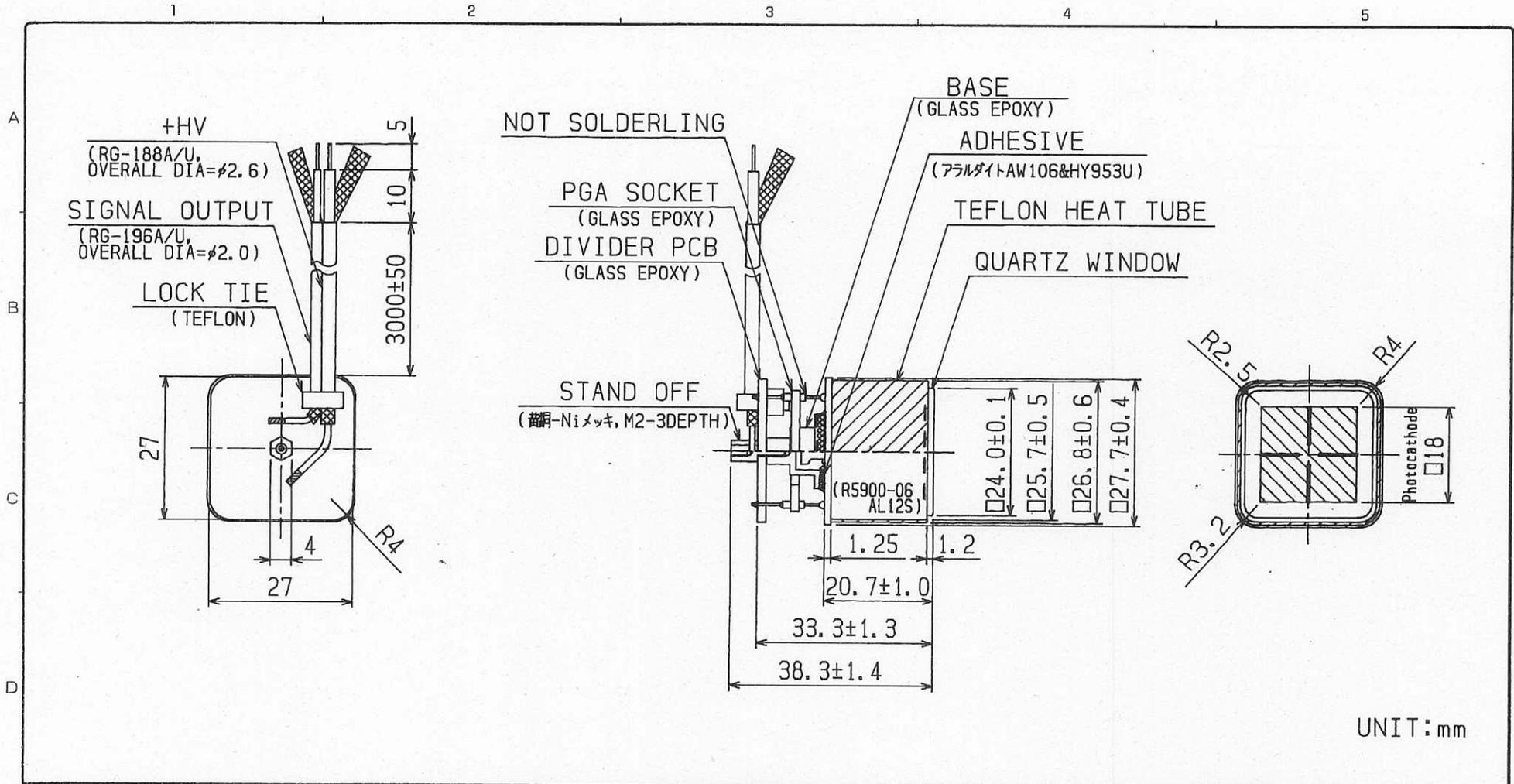
クーリングパイプ付変換ニツプル

or/or

プロトタイプ用TPC

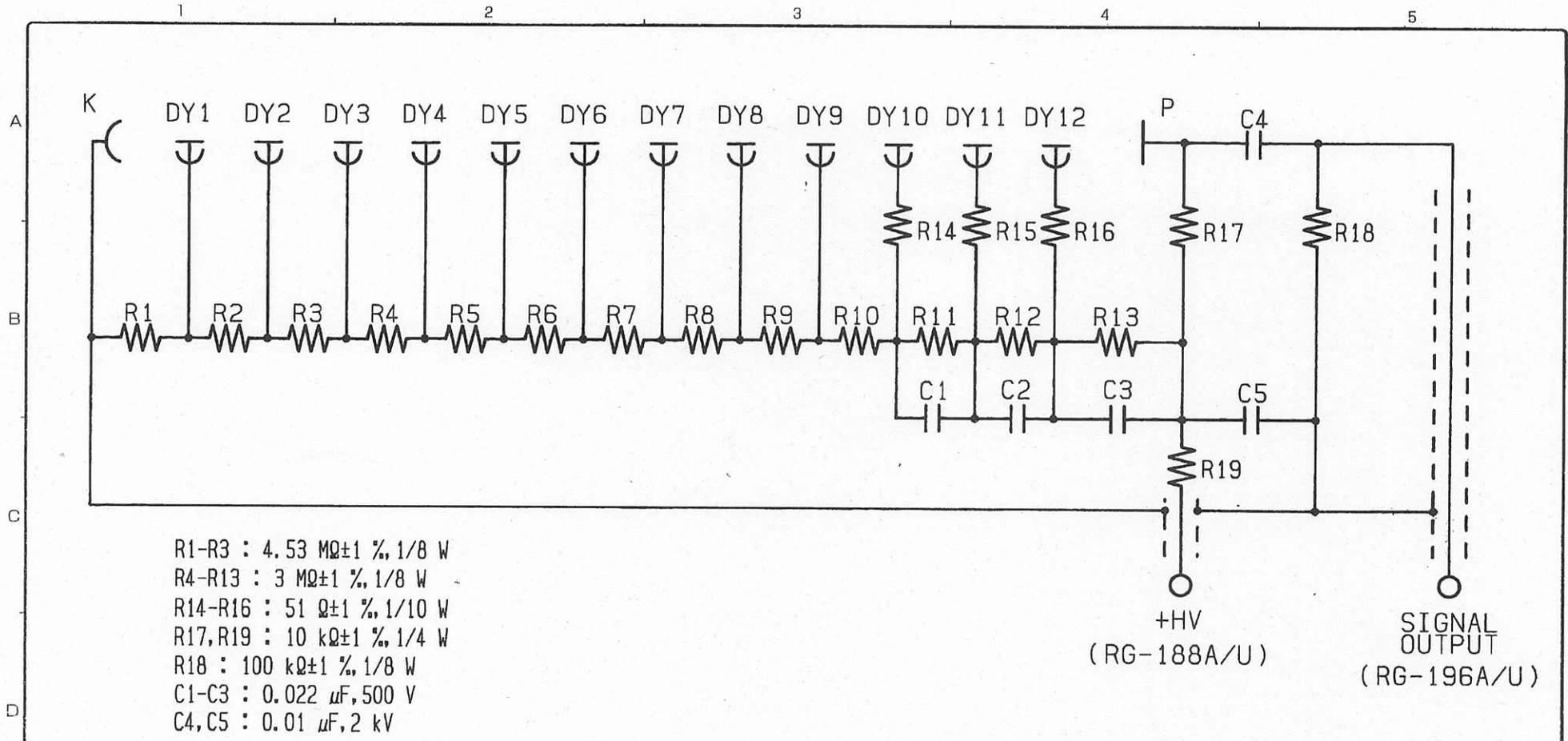
読み出し基盤上に G10の丸棒を立てて
ワイヤーを巻いて電場整形をする。





UNIT:mm

GENERAL TOLERANCE 一般公差				ALT.	MARK	REASON	SIGN.	DATE	MATRL. 材質	SCALE 尺度	DATE 2003.11.28				TITLE 品名
DIMENSION区分	A	B	C							1/1	APPD. 承認	CHCK. 検図	DESN. 設計	DFT. 製図	DIMENSIONAL OUTLINE
≤6	±0.10	±0.20	±0.30												R5900-06AL12S ASSY
6 < ≤30	±0.15	±0.25	±0.50												
30 < ≤120	±0.25	±0.35	±0.80												
120 < ≤500	±0.40	±0.50	±1.40												
500 <	±0.80	±1.00	±2.00												
									TRTM. 処理	PAINT 塗装	DRAW. NO. 図面番号				
											HAMAMATSU PHOTONICS K.K.				21B-058



TOTAL RESISTANCE=43.5 MΩ DIVIDER CURRENT=20.7 μA at +900 V(MAX)

GENERAL TOLERANCE 一般公差				ALT.	MARK	REASON	SIGN.	DATE	MATRL. 材質	SCALE 尺度	DATE 2003.11.28	TITLE 品名 VOLTAGE DIVIDER CIRCUIT R5900-06AL12S ASSY
DIMENSION 区分	A	B	C									
≤6	±0.10	±0.20	±0.30									DRAW. NO. 図面番号 21B-059
6 < ≤30	±0.15	±0.25	±0.50									
30 < ≤120	±0.25	±0.35	±0.80									
120 < ≤500	±0.40	±0.50	±1.40									
500 <	±0.80	±1.00	±2.00									

APPD. 承認
 CHCK. 検図
 DESN. 設計
 DFT. 製図
 渡辺 大津 S.Suguchi S.Suguchi
 HAMAMATSU PHOTONICS K.K.